

COPY

PATENT
3887-0114P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: KIM, Kyong-Min et al. Conf.:
Appl. No.: New Group:
Filed: June 12, 2002 Examiner:
For: METHOD FOR FABRICATING CAPACITOR OF
SEMICONDUCTOR MEMORY DEVICE

L E T T E R

Assistant Commissioner for Patents
Washington, DC 20231

June 12, 2002

Sir:

Under the provisions of 35 U.S.C. § 119 and 37 C.F.R. § 1.55(a), the applicant(s) hereby claim(s) the right of priority based on the following application(s):

<u>Country</u>	<u>Application No.</u>	<u>Filed</u>
KOREA	2001-32686	June 12, 2001

A certified copy of the above-noted application(s) is(are) attached hereto.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to Deposit Account No. 02-2448 for any additional fee required under 37 C.F.R. §§ 1.16 or 1.17; particularly, extension of time fees.

Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

By COPY
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Attachment